

Quad Picoampere Input Current Bipolar Op Amp

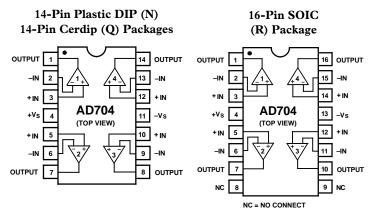
AD704

FEATURES

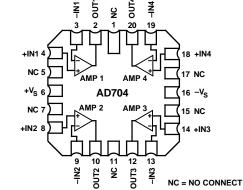
High DC Precision
75 μV max Offset Voltage
1 μV/°C max Offset Voltage Drift
150 pA max Input Bias Current
0.2 pA/°C typical I_B Drift
Low Noise
0.5 μV p-p typical Noise, 0.1 Hz to 10 Hz
Low Power
600 μA max Supply Current per Amplifier
Chips & MIL-STD-883B Processing Available
Available in Tape and Reel in Accordance
with EIA-481A Standard
Single Version: AD705, Dual Version: AD706
PRIMARY APPLICATIONS
Industrial/Process Controls

Industrial/Process Controls Weigh Scales ECG/EKG Instrumentation Low Frequency Active Filters

CONNECTION DIAGRAMS



(E) Package 20-Terminal LCC



Since it has only 1/20 the input bias current of an AD OP07, the AD704 does not require the commonly used "balancing" resistor. Furthermore, the current noise is 1/5 that of the AD OP07 which makes the AD704 usable with much higher source impedances. At 1/6 the supply current (per amplifier) of the AD OP07, the AD704 is better suited for today's higher density circuit boards and battery powered applications.

The AD704 is an excellent choice for use in low frequency active filters in 12- and 14-bit data acquisition systems, in precision instrumentation, and as a high quality integrator. The AD704 is internally compensated for unity gain and is available in five performance grades. The AD704J and AD704K are rated over the commercial temperature range of 0°C to +70°C. The AD704A and AD704B are rated over the industrial temperature of -40° C to +85°C. The AD704T is rated over the military temperature range of -55° C to +125°C and is available processed to MIL-STD-883B, Rev. C.

PRODUCT DESCRIPTION

The AD704 is a quad, low power bipolar op amp that has the low input bias current of a BiFET amplifier but which offers a significantly lower I_B drift over temperature. It utilizes Superbeta bipolar input transistors to achieve picoampere input bias current levels (similar to FET input amplifiers at room temperature), while its I_B typically only increases by $5 \times$ at +125°C (unlike a BiFET amp, for which I_B doubles every 10°C resulting in a 1000× increase at +125°C). Furthermore the AD704 achieves 75 µV offset voltage and low noise characteristics of a precision bipolar input op amp.

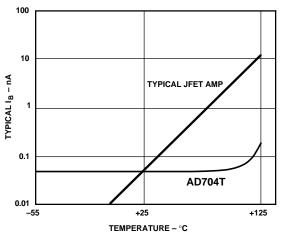


Figure 1. Input Bias Current Over Temperature

REV. A

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One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A. Tel: 617/329-4700 Fax: 617/326-8703

AD704—SPECIFICATIONS (@ $T_A = +25^{\circ}C$, $V_{CM} = 0$ V, and ± 15 V dc, unless otherwise noted)

Model		AD704J/A		AD704K/B			AD704T				
	Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
INPUT OFFSET VOLTAGE Initial Offset Offset vs. Temp, Average TC vs. Supply (PSRR) T _{MIN} -T _{MAX} Long Term Stability	$T_{MIN}-T_{MAX}$ $V_{S} = \pm 2 \text{ to } \pm 18 \text{ V}$ $V_{S} = \pm 2.5 \text{ to } \pm 18 \text{ V}$	100 100	50 100 0.2 132 126 0.3	150 250 1.5	112 108	30 50 0.2 132 126 0.3	75 150 1.0	112 108	30 80 132 126 0.3	100 150 1.0	μV μV μV/°C dB dB μV/month
INPUT BIAS CURRENT ¹ vs. Temp, Average TC $T_{MIN}-T_{MAX}$ $T_{MIN}-T_{MAX}$	$V_{CM} = 0 V$ $V_{CM} = \pm 13.5 V$ $V_{CM} = 0 V$ $V_{CM} = \pm 13.5 V$		100 0.3	270 300 300 400		80 0.2	150 200 200 300		80 1.0	200 250 600 700	pA pA pA/°C pA pA
INPUT OFFSET CURRENT vs. Temp, Average TC $T_{MIN}-T_{MAX}$ $T_{MIN}-T_{MAX}$	$V_{CM} = 0 V$ $V_{CM} = \pm 13.5 V$ $V_{CM} = 0 V$ $V_{CM} = \pm 13.5 V$		80 0.6 100 100	250 300 300 400		30 0.4 80 80	100 150 200 300		50 0.4 80 100	150 200 400 500	pA pA pA/°C pA pA
MATCHING CHARACTERISTICS Offset Voltage Input Bias Current ² Common-Mode Rejection ³ Power Supply Rejection ⁴ Crosstalk ⁵	$T_{MIN}-T_{MAX}$ $T_{MIN}-T_{MAX}$ $T_{MIN}-T_{MAX}$ $T_{MIN}-T_{MAX}$ $f = 10 Hz$ $R_{LOAD} = 2 k\Omega$	94 94 94 94	150	250 400 500 600	110 104 110 106	150	130 200 300 400	104 104 110 106	150	150 250 400 600	μV μV pA dB dB dB dB dB
FREQUENCY RESPONSE UNITY GAIN Crossover Frequency Slew Rate, Unity Gain Slew Rate	$G = -1$ $T_{MIN} - T_{MAX}$		0.8 0.15 0.1			0.8 0.15 0.1			0.8 0.15 0.1		MHz V/μs V/μs
INPUT IMPEDANCE Differential Common-Mode			40 2 300 2			40 2 300 2			40 2 300 2		$M\Omega \ pF$ $G\Omega \ pF$
INPUT VOLTAGE RANGE Common-Mode Voltage Common-Mode Rejection Ratio	$V_{CM} = \pm 13.5 V$ $T_{MIN} - T_{MAX}$	±13.5 100 98	±14 132 128		±13.5 114 108	±14 132 128		±13.5 110 108	±14 132 128		V dB dB
INPUT CURRENT NOISE	0.1 to 10 Hz f = 10 Hz		3 50			3 50			3 50		pA p-p fA/√Hz
INPUT VOLTAGE NOISE	0.1 to 10 Hz f = 10 Hz f = 1 kHz		0.5 17 15	22		0.5 17 15	2.0 22		0.5 17 15	2.0 22	$ \begin{array}{c} \mu V \ p\text{-}p \\ nV/\sqrt{Hz} \\ nV/\sqrt{Hz} \end{array} $
OPEN-LOOP GAIN	$V_{O} = \pm 12 V$ $R_{LOAD} = 10 k\Omega$ $T_{MIN} - T_{MAX}$ $V_{O} = \pm 10 V$ $P_{O} = -2 k\Omega$	200 150	2000 1500		400 300	2000 1500		400 300	2000 1500		V/mV V/mV
	$R_{\text{LOAD}} = 2 \text{ k}\Omega$ $T_{\text{MIN}} - T_{\text{MAX}}$	200 150	1000 1000		300 200	1000 1000		200 100	1000 1000		V/mV V/mV

Model	AD704J/A			AD704K/B			AD704T				
	Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
OUTPUT CHARACTERISTICS											
Voltage Swing	$R_{LOAD} = 10 k\Omega$										
	T _{MIN} -T _{MAX}	±13	± 14		±13	± 14		±13	± 14		V
Current	Short Circuit		±15			±15			±15		mA
CAPACITIVE LOAD											
Drive Capability	Gain = + 1		10,00	0		10,00	00		10,00	0	pF
POWER SUPPLY											
Rated Performance			±15			±15			±15		V
Operating Range		±2.0		± 18	±2.0		± 18	±2.0		± 18	V
Quiescent Current			1.5	2.4		1.5	2.4		1.5	2.4	mA
	T _{MIN} -T _{MAX}		1.6	2.6		1.6	2.6		1.6	2.6	mA
TRANSISTOR COUNT	# of Transistors		180			180			180		

NOTES

¹Bias current specifications are guaranteed maximum at either input.

²Input bias current match is the maximum difference between corresponding inputs of all four amplifiers.

 ${}^{3}CMRR$ match is the difference of $\Delta V_{OS}/\Delta V_{CM}$ between any two amplifiers, expressed in dB.

⁴PSRR match is the difference between $\Delta V_{OS}/\Delta V_{SUPPLY}$ for any two amplifiers, expressed in dB.

⁵See Figure 2a for test circuit.

All min and max specifications are guaranteed.

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS¹

Supply Voltage $\pm 18 \text{ V}$
Internal Power Dissipation (+25°C) See Note 2
Input Voltage $\dots \dots \pm V_S$
Differential Input Voltage ³ ±0.7 V
Output Short Circuit Duration (Single Input) Indefinite
Storage Temperature Range
(Q) -65° C to $+150^{\circ}$ C
(N, R) -65° C to $+125^{\circ}$ C
Operating Temperature Range
AD704J/K \cdots 0°C to +70°C
AD704A/B $\dots -40^{\circ}$ C to $+85^{\circ}$ C
AD704T –55°C to +125°C
Lead Temperature Range (Soldering 10 seconds) +300°C

NOTES

¹Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. ²Specification is for device in free air:

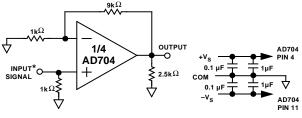
14-Pin Plastic Package: $\theta_{JA} = 150^{\circ}C/Watt$

14-Pin Cerdip Package: $\theta_{JA} = 110^{\circ}C/Watt$

16-Pin SOIC Package: $\theta_{JA} = 100^{\circ}C/Watt$

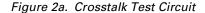
20-Terminal LCC Package: $\theta_{JA} = 150^{\circ}$ C/Watt

³The input pins of this amplifier are protected by back-to-back diodes. If the differential voltage exceeds ± 0.7 volts, external series protection resistors should be added to limit the input current to less than 25 mA.



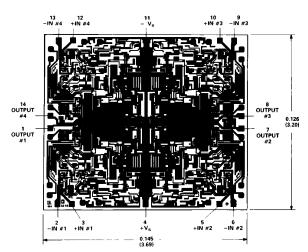
ALL 4 AMPLIFIERS ARE CONNECTED AS SHOWN

*THE SIGNAL INPUT (SUCH THAT THE AMPLIFIER'S OUTPUT IS AT MAX AMPLITUDE WITHOUT CLIPPING OR SLEW LIMITING) IS APPLIED TO ONE AMPLIFIER AT A TIME. THE OUTPUTS OF THE OTHER THREE AMPLIFIERS ARE THEN MEASURED FOR CROSSTALK.



METALIZATION PHOTOGRAPH

Dimensions shown in inches and (mm). Contact factory for latest dimensions.



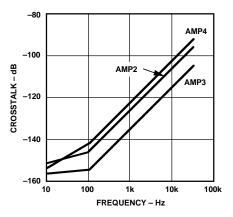


Figure 2b. Crosstalk vs. Frequency

AD704—Typical Characteristics (@ +25°C, V_s = ±15 V, unless otherwise noted)

Model	Temperature Range	Package Option*
AD704JN	0°C to +70°C	N-14
AD704JR	0°C to +70°C	R-16
AD704JR-/REEL	0°C to +70°C	Tape and Reel
AD704KN	0°C to +70°C	N-14
AD704AN	-40°C to +85°C	N-14
AD704AQ	–40°C to +85°C	Q-14
AD704AR	-40°C to +85°C	R-16
AD704AR-REEL	–40°C to +85°C	Tape and Reel
AD704BQ	–40°C to +85°C	Q-14
AD704SE/883B	–55°C to +125°C	E-20A
AD704TQ	–55°C to +125°C	Q-14
AD704TQ/883B	–55°C to +125°C	Q-14

ORDERING GUIDE

Chips are also available.

*E = Leadless Ceramic Chip Carrier; N = Plastic DIP; Q = Cerdip;

R = Small Outline (SOIC).

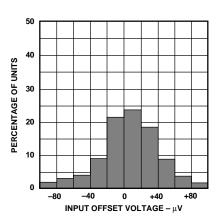


Figure 3. Typical Distribution of Input Offset Voltage

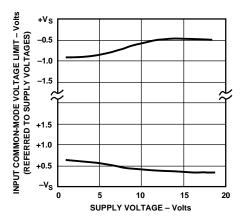


Figure 6. Input Common-Mode Voltage Range vs. Supply Voltage

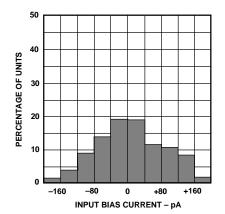


Figure 4. Typical Distribution of Input Bias Current

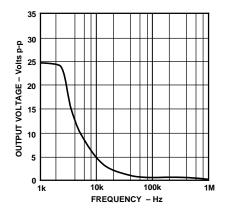


Figure 7. Large Signal Frequency Response

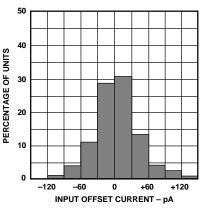


Figure 5. Typical Distribution of Input Offset Current

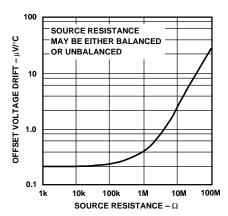


Figure 8. Offset Voltage Drift vs. Source Resistance

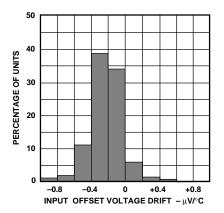


Figure 9. Typical Distribution of Offset Voltage Drift

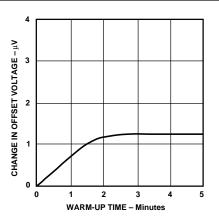


Figure 10. Change in Input Offset Voltage vs. Warm-Up Time

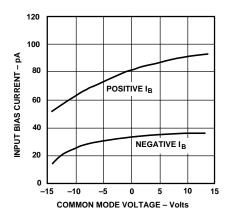


Figure 11. Input Bias Current vs. Common-Mode Voltage

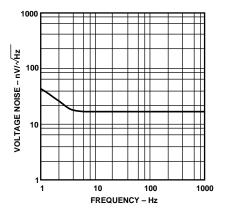


Figure 12. Input Noise Voltage Spectral Density

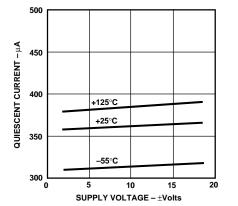


Figure 15. Quiescent Supply Current vs. Supply Voltage (per Amplifier)

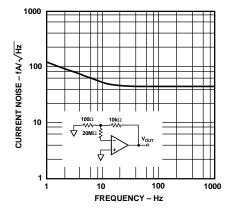


Figure 13. Input Noise Current Spectral Density

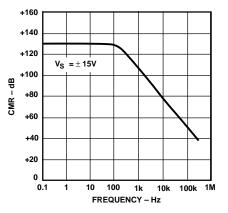


Figure 16. Common-Mode Rejection vs. Frequency

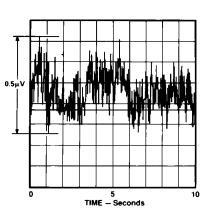


Figure 14. 0.1 Hz to 10 Hz Noise Voltage

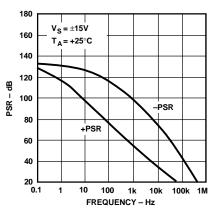


Figure 17. Power Supply Rejection vs. Frequency

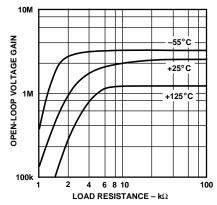


Figure 18. Open-Loop Gain vs. Load Resistance Over Temperature

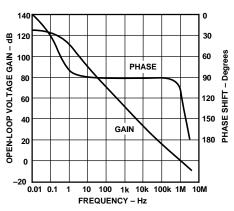


Figure 19. Open-Loop Gain and Phase vs. Frequency

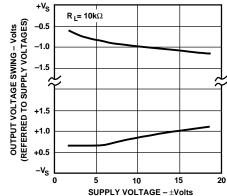


Figure 20. Output Voltage Swing vs. Supply Voltage

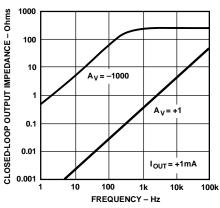
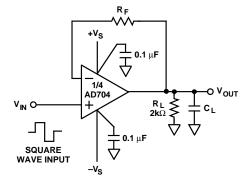
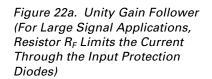


Figure 21. Closed-Loop Output Impedance vs. Frequency





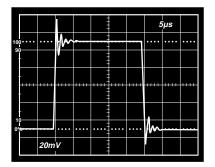


Figure 22d. Unity Gain Follower Small Signal Pulse Response $R_F = 0 \Omega$, $C_L = 1,000 \text{ pF}$

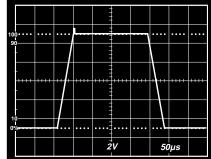


Figure 22b. Unity Gain Follower Large Signal Pulse Response $R_F = 10 \ k\Omega, \ C_L = 1,000 \ pF$

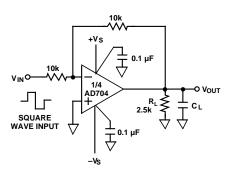


Figure 23a. Unity Gain Inverter Connection

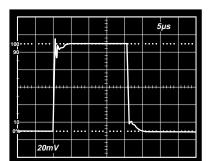


Figure 22c. Unity Gain Follower Small Signal Pulse Response $R_F = 0 \Omega$, $C_L = 100 \text{ pF}$

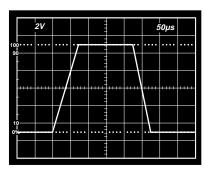


Figure 23b. Unity Gain Inverter Large Signal Pulse Response, $C_L = 1,000 \text{ pF}$

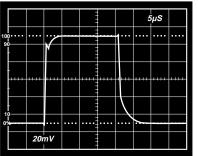


Figure 23c. Unity Gain Inverter Small Signal Pulse Response, CL = 100 pF

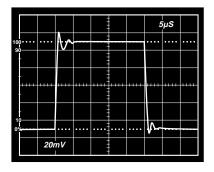


Figure 23d. Unity Gain Inverter Small Signal Pulse Response, $C_L = 1,000 \text{ pF}$

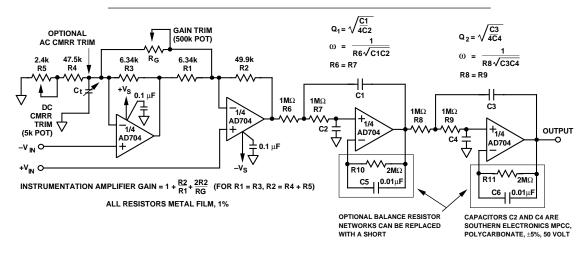


Figure 24. Gain of 10 Instrumentation Amplifier with Post Filtering

The instrumentation amplifier with post filtering (Figure 24) combines two applications which benefit greatly from the AD704. This circuit achieves low power and dc precision over temperature with a minimum of components.

The instrumentation amplifier circuit offers many performance benefits including BiFET level input bias currents, low input offset voltage drift and only 1.2 mA quiescent current. It will operate for gains $G \ge 2$, and at lower gains it will benefit from the fact that there is no output amplifier offset and noise contribution as encountered in a 3 op amp design. Good low frequency CMRR is achieved even without the optional AC CMRR trim (Figure 25). Table I provides resistance values for 3 common circuit gains. For other gains, use the following equations:

$$R2 = R4 + R5 = 49.9 \ k\Omega$$
$$R1 = R3 = \frac{49.9 \ k\Omega}{0.9 \ G - 1}$$

Max Value of $R_G = \frac{99.8 k}{0.06 G}$

$$C_t \approx \frac{1}{2 \pi (R3) 5 \times 10^5}$$

Table I. Resistance Values for Various Gains

Circuit Gain (G) R1 & R3		R _G (Max Value of Trim Potentiometer)	Bandwidth (-3 dB), Hz		
10	6.34 kΩ	166 kΩ	50k		
100	526 Ω	16.6 kΩ	5k		
1,000	56.2 Ω	1.66 kΩ	0.5k		

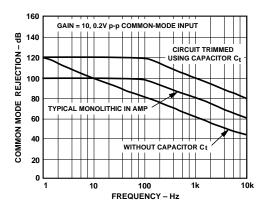


Figure 25. Common-Mode Rejection vs. Frequency with and without Capacitor C_t

The 1 Hz, 4-pole active filter offers dc precision with a minimum of components and cost. The low current noise, I_{OS} , and I_B allow the use of 1 M Ω resistors without sacrificing the 1 μ V/°C drift of the AD704. This means lower capacitor values may be used, reducing cost and space. Furthermore, since the AD704's I_B is as low as its I_{OS} , over most of the MIL temperature range, most applications do not require the use of the normal balancing resistor (with its stability capacitor). Adding the optional balancing resistor enhances performance at high temperatures, as shown in Figure 26. Table II gives capacitor values for several common low pass responses.

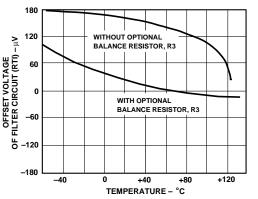


Figure 26. V_{OS} vs. Temperature Performance of the 1 Hz Filter Circuit

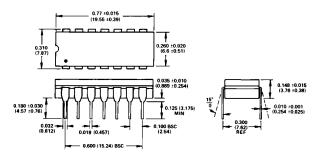
Desired Low Pass Response	Section 1 Frequency (Hz)	Q	Section 2 Frequency (Hz)	Q	C1 (µF)	C2 (μF)	C3 (µF)	C4 (μF)
Bessel	1.43	0.522	1.60	0.806	0.116	0.107	0.160	0.0616
Butterworth	1.00	0.541	1.00	1.31	0.172	0.147	0.416	0.0609
0.1 dB Chebychev	0.648	0.619	0.948	2.18	0.304	0.198	0.733	0.0385
0.2 dB Chebychev	0.603	0.646	0.941	2.44	0.341	0.204	0.823	0.0347
0.5 dB Chebychev	0.540	0.705	0.932	2.94	0.416	0.209	1.00	0.0290
1.0 dB Chebychev	0.492	0.785	0.925	3.56	0.508	0.206	1.23	0.0242

Specified Values are for a -3 dB point of 1.0 Hz. For other frequencies simply scale capacitors C1 through C4 directly; i.e., for 3 Hz Bessel response, C1 = 0.0387 μ F, C2 = 0.0357 μ F, C3 = 0.0533 μ F, C4 = 0.0205 μ F.

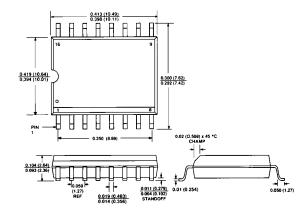
OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

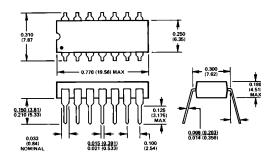
14-Pin Cerdip (Q) Package



16-Pin Plastic SO (R) Package



14-Pin Plastic DIP (N) Package



20-Terminal LCCC (E) Package

